IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

Tu, et al.

Attorney Docket: TSM03-0426

Filed:

Herewith

Examiner:

TBD

Serial No.:

TBD

Art Unit:

TBD

For:

MIM Capacitor Structure and Method of Manufacture

Mail Stop: Patent Application Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

The Applicants wish to bring to the attention of the Patent and Trademark Office the information noted on the enclosed form PTO/SB/08A that may be considered material to the examination of the above-identified application.

No fee is due at this time, as this Information Disclosure Statement is being filed concurrently with the patent application.

Respectfully submitted,

October 20, 2003

Date

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PTO/SB/08A (05-03)
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Substitute for form 1449A/PTO				Compl te if Known		
				Application Number	TBD	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Filing Date	Herewith	
				First Named Inventor	Tu, et al.	
				Art Unit	TBD	
(use as many sheets as necessary)			cessary)	Examiner Name	TBD	
Sheet	11	of	11	Attorney Docket Number	TSM03-0426	

U.S. PATENT DOCUMENTS						
Examiner Initials*	Cite No.1	Document Number	Publication Date	Name of Patentee or	Pages, Columns, Lines, Where	
		Number - Kind Code ^{2 (# known)}	MM-DD-YYYY	Applicant of Cited Document	Relevant Passages or Relevant Figures Appear	
	1	US-6,051,462 A	04-18-2000	Ohno		
	2	US-6,281,540 B1	08-28-2001	Aoki		
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		Foreign Patent Document	Dublication Date	Name of Patentee or	Pages, Columns, Lines,	
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OTHER PRIOR ART NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite ₁ No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			
	9	LIU, et al., Single Mask Metal-Insulator-Metal (MIM) Capacitor with Copper Damascene Metallization for Sub-0.18µm Mixed Mode Signal and System-on-a-Chip (SoC) Applications, 2000, Lucent Technologies Bell Laboratories, Murray Hill, NJ, US.			
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Examiner	Date	
Signature	Considered	
		<u> </u>

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. ¹Applicant's unique citation designation number (optional). ²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). *For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language Translation is attached.

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